PNP Epitaxial Planar Silicon Transistor

2SA1437



High-hfe, AF Amplifier Applications

Applications

· AF amplifier, various drivers, muting circuit.

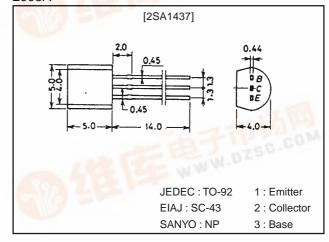
Features

- Very small-sized package permitting sets to be made smaller and slimer.
- · Adoption of FBET process.
- · High DC current gain: (h_{FE}=400 to 1000).
- · High breakdown voltage : (V_{CEO}≥100V).
- · Low collector-to-emitter saturation voltage
 - $: (\mathbf{V}_{\mathbf{CE}(\mathbf{sat})} \leq 0.5\mathbf{V}).$
- · High V_{EBO} : $(V_{EBO} \ge 15V)$.
- · Small C_{ob} : (C_{ob} =4.0pF typ).

Package Dimensions

unit:mm

2003A



Specifications

Absolute Maximum Ratings at Ta = 25°C

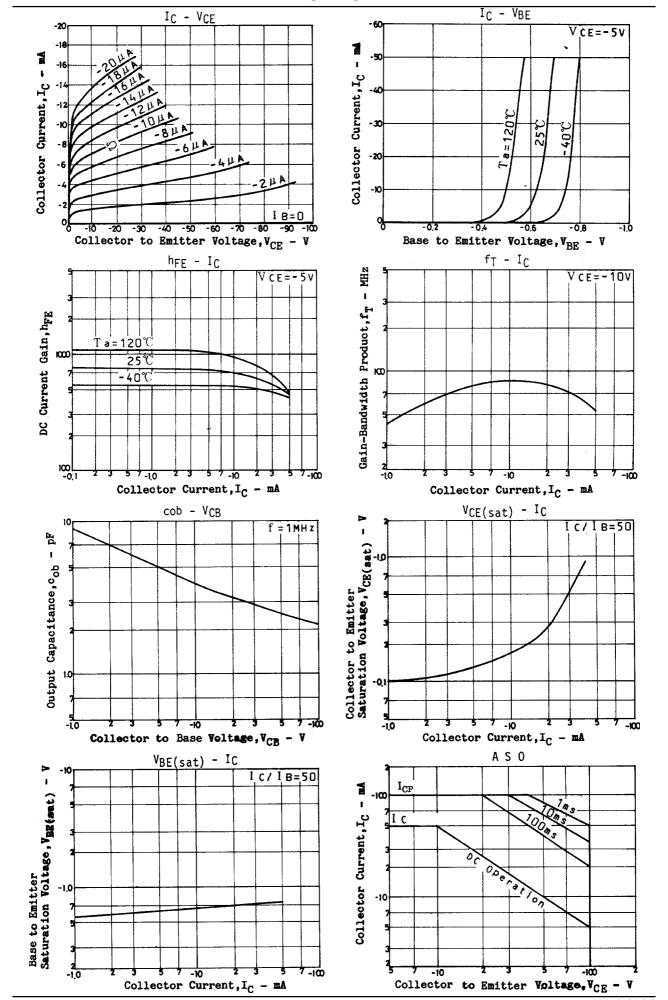
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		-120	V
Collector-to-Emitter Voltage	VCEO		-100	V
Emitter-to-Base Voltage	VEBO		-15	V
Collector Current	Ic		-50	mA
Collector Current (Pulse)	I _{CP}		-100	mA
Collector Dissipation	PC		500	mW
Junction Temperature	Tj	800 7 1 5 2 5	150	°C
Storage Temperature	Tstg	EN (0) =	-55 to +150	°C

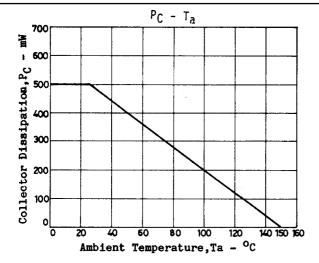
Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		Ratings		
	Syllibol		min	typ	max	Unit
Collector Cutoff Current	I _{CBO}	V _{CB} =-80V, I _E =0			-0.1	μΑ
Emitter Cutoff Current	I _{EBO}	V _{EB} =-10V, I _C =0			-0.1	μA
DC Current Gain	h _{FE}	V _{CE} =-5V, I _C =-10mA	400	700	1000	
Gain-Bandwidth Product	f _T	V _{CE} =-10V, I _C =-10mA	11	85		MHz
Output Capacitance	C _{ob}	V _{CB} =-10V, f=1MHz	123	4.0	ac.	pF
Collector-to-Emitter Saturation Voltage	VCE(sat)	I _C =-10mA, I _B =-0.2mA		-0.18	-0.5	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =-10mA, I _B =-0.2mA	- 41	-0.7	-1.0	V
Collector-to-Base Breakdown Voltage	V _(BR) CBO	I _C =-10μA, I _E =0	-120			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =-1mA, R _{BE} =∞	-100			V
Emitter-to-Base Breakdown Votage		I _E =-10μA, I _C =0	-15			V

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SANYO Electric Co.,Ltd. Semiconductor Bussiness Headquaters
TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN





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